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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

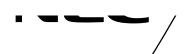
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MOS FIELD EFFECT TRANSISTOR 2SK4212

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4212 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

• Low on-state resistance

 $R_{DS(on)1} = 7.8 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, Ip} = 30 \text{ A)}$

 $R_{DS(on)2} = 14 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 4.5 \text{ V, Ip} = 20 \text{ A)}$

Low total gate charge

 $Q_G = 27 \text{ nC TYP.}$ ($V_{DD} = 15 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 30 \text{ A}$)

- 4.5 V drive available
- Avalanche capability ratings

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
2SK4212-ZK-E1-AY Note	Duna Ca (Tia)	Tene 2500 m/m al	TO 050 (MD 07K) him 0 07 m	
2SK4212-ZK-E2-AY Note	Pure Sn (Tin)	Tape 2500 p/reel	TO-252 (MP-3ZK) typ. 0.27 g	

Note Pb-free (This product does not contain Pb in external electrode).

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	25	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±48	Α
Drain Current (pulse) Note1	D(pulse)	±144	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	35	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	17	Α
Single Avalanche Energy Note2	Eas	28.9	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 12.5 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 0.1 mH



(TO-252)

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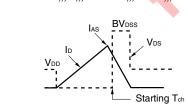
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V _{DS} = 25 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.5		3.0	V
Forward Transfer Admittance Note	yfs	V _{DS} = 5 V, I _D = 12 A	10	22		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 30 A		5.5	7.8	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 20 A		8.5	14	mΩ
Input Capacitance	Ciss	V _{DS} = 15 V,		1200		pF
Output Capacitance	Coss	V _{GS} = 0 V,		220		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		140		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 30 A,		16		ns
Rise Time	tr	V _{GS} = 10 V,		14		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 3 \Omega$		45		ns
Fall Time	tr			11		ns
Total Gate Charge	Q _G	V _{DD} = 15 V,		27		nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V,		4		nC
Gate to Drain Charge	Q _{GD}	In = 30 A		7		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 30 A, VGS = 0 V		0.88	1.5	V
Reverse Recovery Time	trr	IF = 30 A, VGS = 0 V,		26		ns
Reverse Recovery Charge	Qn	di/dt = 100 A /μs	_	14		nC

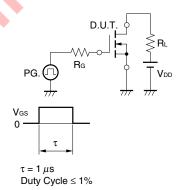
Note Pulsed

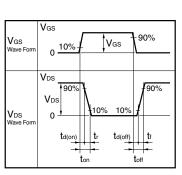
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$\begin{array}{c} \text{D.U.T.} \\ \text{PG.} \\ \text{PG.} \\ \text{\downarrow} \\ \text{$

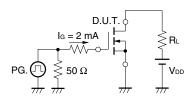


TEST CIRCUIT 2 SWITCHING TIME

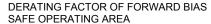


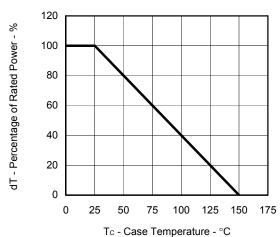


TEST CIRCUIT 3 GATE CHARGE

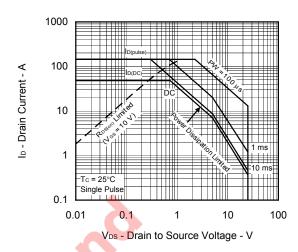


TYPICAL CHARACTERISTICS (TA = 25°C)

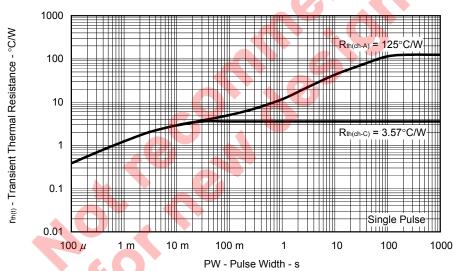




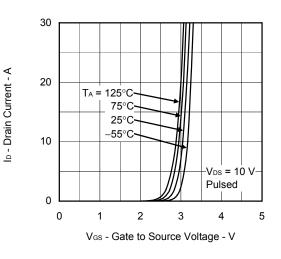
FORWARD BIAS SAFE OPERATING AREA



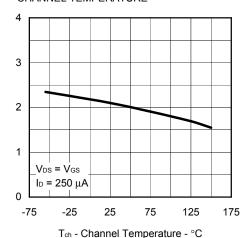
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



FORWARD TRANSFER CHARACTERISTICS

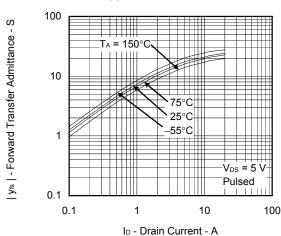


GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

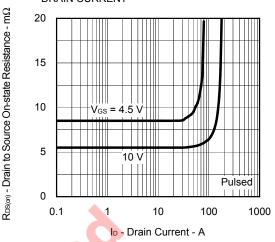


Ves(th) - Gate to Source Threshold Voltage - V

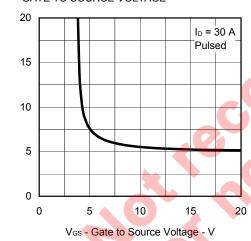




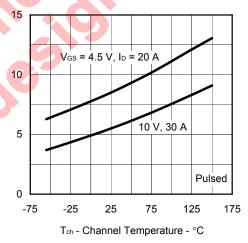
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



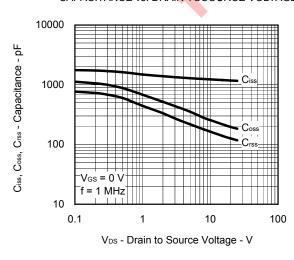
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



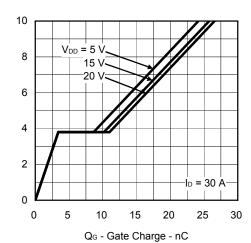
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



CAPACITANCE vs. DRAIN TOSOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

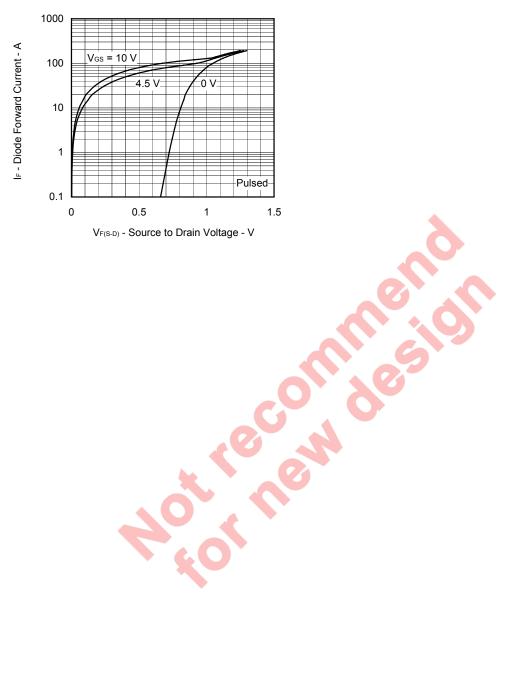


RDS(on) - Drain to Source On-state Resistance - m\Omega

R_{DS(on)} - Drain to Source On-state Resistance - mΩ

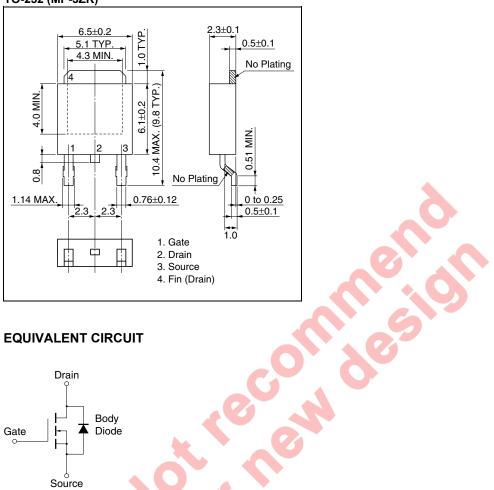
Ves - Gate to Source Voltage - V

SOURCE TO DRAIN DIODE FORWARD VOLTAGE

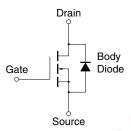


PACKAGE DRAWINGS (Unit: mm)

TO-252 (MP-3ZK)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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